CRYRING 蓄積リング用可変なパルス幅の高速キッカーシステム

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概要

陽電子ビームもその他の荷電粒子ビームもを減速するため、ス トックホルムの Manne Siegbahn Laboratory (MSL)の CRYRING 蓄 積リングは FLAIR 加速器複合体用ダルムシュタットに移られる ようにしている。FLAIR 用のエネルギー範囲 (30Mev-0.13MeV)は 現 在より広がれて、適合させるためにアップグレードが必要で あること。

280ns 以下立ち上がり時間、1.62µs から 16.3µs まで可変なパ ルス幅、3200A まで可変な電流として、出射用キッカ電源は特別 に微妙なシステムとなります。

CRYRING のため SOLEIL と密接に協力し SIGMAPHI によって特別 に開発したキッカは2つパルス電源に基づいて新しい仕組してい ます。まず速い立ち上がり時間は高電圧電源に制御されて、次に 小電圧電源によってフラットトップは決定的な時間を立ち行って 後でパルスはフリーホイー回路で消ています。 各電源が限られ た用事を行うため、普通な PFL/PFN に比べると電圧 (50kV)ではな く、サイラトロンは必要ではなく、20kV ソリッドステートスイ ッチは使用すること可能である。

今回これらの技術課題を達成するための方法と結果について報 告する。

INTRODUCTION

Pulsed power is a technology that usually accumulates energy over a relatively long period and then releases it into a load within a short interval.

Energy stored in a capacitor is often used to obtain sine current waveforms in inductive magnet loads. PFL (Pulse Forming Line) or PFN (Pulse Forming Network) are classically exploited in trapezoidal current waveform generation.

The CRYRING injection system [1][2] must be able to provide a 3200 A trapezoidal current with 280 ns fall time and a fixed duration of 1.62 μ s but the he extraction system requires a variable square current amplitude ranging from 3200 A to 200 A with a pulse duration varying between 1.62 μ s and 16 μ s and a rise time smaller than 280 ns.

Using a PFL-based circuit, the pulse duration dictates the length of the pulse forming line. For our extraction kicker, the 16 µs maximum pulse duration would impose more than 3 km long line. The superimposed need to tailor the impedance to the 12.5Ω characteristic impedance dictated by the 280 ns rise time either calls for specially made cables or to make a parallel arrangement of standard 50 Ω ones, resulting in prohibitive cable length and cost. In addition, the short rise and fall times and the strong current would require a high voltage close to 50 kV, that become delicate for many parts of the circuit like the HV switch especially if solid-state and coaxial cables. However, in PFL/PFN based circuits, this high voltage is an immediate consequence of basic requirements: the magnet directly determines the impedance of the forming line (or forming network) which in turn determines the voltage.

Due to the unusual requirement of the pulses generation with both strength and duration tuning, the development, made specifically for the CRYRING kickers [1][2], is based on a new topology involving two different power supplies, one managing the fast rise time and the other supplying the current flat top. A fast solid state switch controls the triggering and also the pulse duration. The idea of separating the functions is not completely new [3] but, to our knowledge, no pulser actually using it was ever completed and, the topology we propose is different from any of those defined in [3].

Table 1: Main parameters of MSL kickers

System	Injection	Extraction
Estimated maximum current	Fixed 3560~	Adjustable
	3200 A	3200 A to 200 A
Kick rise Time (97% to 3%)	Not relevant	280 ns
Pulse duration	Fixed	Adjustable
	1.62 µs	1.62 µs to 16 µs
Flat top ripple	$\leq \pm 3\%$	$\leq \pm 3\%$
Kick fall Time	280 ns	Not relevant
(97% to 3%)		
Pulse repetition	2 s	2 s

BASIC OPERATION PRINCIPLE

The circuit is described in figure 1.



Figure 1: Kickers circuit schematics.

The kicker pulsed circuit associates a high voltage discharge circuit designed to provide the fast rise time, a large capacitor value that supplies the flat top high current and a free wheel circuit managing the current decrease duration. The kicker systems are built in such a way that the kick amplitude and pulse length are variable.

Initially, the switch T is open. The capacitor C_{HV} is charged through the resistor R_{HV} to a voltage E_{HV} in a time lower than the repetition time. The voltage across the capacitor C_{LV} is maintained constant by the power supply E_{LV} .

At switch T closure, a resonant circuit is formed by the $C_{\rm HV}$ capacitor and the $L_{\rm magnet}$ inductance. A sinusoidal current starts rising in the inductive load, accompanied by a concomitant voltage drop in the high voltage capacitor. The current evolution is described by the simplified equation:

$$i_L(t) = E_{HV} \sqrt{\frac{C_{HV}}{L}} \sin \omega_1 t$$
 with $\omega_1 = \frac{1}{\sqrt{LC_{HV}}}$

L being the impedance and ω_1 the resonant pulsation.

The rise time, defined as the time it takes for the magnetic field in the kicker magnet to rise from 3% to 97%, imposes the maximum permitted C_{HV} capacitance

$$C_{HV} = \frac{1}{L} \left(\frac{100 * T_{rise}}{94} \frac{2}{\pi} \right)^2$$

This also determines the input high voltage source $E_{\rm HV}$ needed to obtain the required maximum current amplitude

$$i_{LMAX} = E_{HV} \sqrt{\frac{C_{HV}}{L}}$$

Once the required peak current amplitude is reached, the C_{HV} capacitor's voltage is near the E_{LV} value and the diode D_{LV} begins to conduct. After the overlap time between the D_{HV} and D_{LV} diodes, the low voltage circuit controls the flat top current in the magnet. During the flat top period, the low voltage constant source E_{LV} delivers the current to the load. The knowledge of the circuit resistance (R) value gives the source constraint

$$E_{LV} = R \cdot i_{LMAX}$$

Once the pulse duration is achieved, the switch T is opened, and the fall time control is handed over to the free wheel circuit in which suitable choice of Z_w components' value forces the load current to decrease in a predetermined duration, at the end of which the current is interrupted at the zero crossing by the opening of the D_w diode.

EVALUATION OF THE TOPOLOGY

The switching device plays an important role in the performance of the system, affecting rise time, jitter, and fall time and a specific printed circuit board based on multiple small fast IGBTs series-parallel association was developped. The advent of these new solid-state switches, exhibiting high-current and high-voltage capability to open or close the circuit with enough speed permits to avoid driving Thyratrons classically exploited in pulsed systems. In the case of the extraction system, the resonant period of the discharge is very short, imposing an upper limit on the storing energy capacitance $C_{\rm HV}$ (given that the magnet inductance is fixed) and so it demands charging voltages above 20kV to achieve the required peak magnet current, with consequent large and costly hardware. Although large, these voltage values remain within acceptable limits in comparison to the 50kV required in a conventional PFL topology.

One end of the magnet is connected to the pulsed positive voltage and the other end is connected to ground where the current is monitored using a Bergoz current transformer. This permits using coaxial cable from the high voltage pulsed power supply to the magnet to control the transmission impedance. Kick reversal is possible with a dedicated magnet interface.

To verify the performance of this circuit, a prototype able to be adapted to injection or extraction requirements has been built, tuned and tested.

Figure 2 gives a general view of the prototype pulser during assembly and figure 3 gives a closer view on the high voltage switch in injection configuration.



Figure 2: The prototype pulser during assembly.



Figure 3: The HV switch in injection configuration.

PERFORMANCES

To verify the performances, the prototype pulser is connected to an inductance representative of the kicker magnets.

Case of the Fully Tuneable Extraction Kicker

The key parameters in the performances required for the extraction kicker are the T_{rise} and the variability in pulse duration and amplitude.

With a small capacitor $C_{\rm HV}$ value, we measure the curves shown in figure 4, demonstrating the ability to respect the adequate performance near the nominal point.



Figure 4: Trise measurement for the extraction kicker.

The measurements also permit to demonstrate the pulse width flexibility of the realisation, with full adjusting of the pulses both in amplitude and duration in all the required range (figure 5). It is worth mentioning that in this case, where the falling time is not relevant, no effort is made to shorten the fall time of the pulse current and a simple diode is used as free wheel circuit. Shorter fall time could be achieved if needed.



Figure 5: Variable pulse width and amplitude of the extraction kicker.

Case of the Injection Kicker

The key requirement of the injection system is the fall time of the pulse current. The pulse duration and nominal amplitude are fixed. In a second arrangement of the prototype pulser, for the capacitor C_{HV} a higher value is introduced to limit the high voltage requirement with an acceptable T_{rise} . Work was done to obtain the required T_{fall} (≤ 280 ns) by an effort on the free wheel circuit adaptation. The injection kicker full pulse at 3660A is presented in figure 6.



Figure 6: Injection kicker full pulse.

CONCLUSIONS

The realization of these kicker magnets systems bring out the big advantages of this innovative scheme.

In the case of the extraction kicker, which has to accommodate non-relativistic beams of variable energy, from 130 keV to 30 MeV, it gives a very flexible solution in which both peak amplitude and width of the high current pulses can be adjusted, using only the two charging power supplies settings and the ON/OFF triggering times of the HV switch assembly.

Using available high current-high voltage switches, based on fast IGBTs, allows having a simple control of the pulse width and of the pulse triggering with low jitter.

For both injection and extraction kickers systems, this technology results in a much cheaper and much more compact solution than a classical PFL system.

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